



Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at
www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.



FNA27560

600 V Motion SPM® 2 Series

Features

- UL Certified No. E209204 (UL1557)
- 600 V - 75 A 3-Phase IGBT Inverter, Including Control ICs for Gate Drive and Protections
- Low-Loss, Short-Circuit-Rated IGBTs
- Very Low Thermal Resistance Using Al₂O₃ DBC Substrate
- Built-In Bootstrap Diodes and Dedicated Vs Pins Simplify PCB Layout
- Separate Open-Emitter Pins from Low-Side IGBTs for Three-Phase Current Sensing
- Single-Grounded Power Supply Supported
- Built-In NTC Thermistor for Temperature Monitoring and Management
- Adjustable Over-Current Protection via Integrated Sense-IGBTs
- Isolation Rating of 2500 Vrms / 1 min.

Applications

- Motion Control - Industrial Motor (AC 200 V Class)

Related Resources

- [AN-9121 - Users Guide for 600V SPM® 2 Series](#)
- [AN-9076 - Mounting Guide for New SPM® 2 Package](#)
- [AN-9079 - Thermal Performance of Motion SPM® 2 Series by Mounting Torque](#)

General Description

The FNA27560 is a Motion SPM® 2 module providing a fully-featured, high-performance inverter output stage for AC induction, BLDC, and PMSM motors. These modules integrate optimized gate drive of the built-in IGBTs to minimize EMI and losses, while also providing multiple on-module protection features: under-voltage lockouts, over-current shutdown, temperature sensing, and fault reporting. The built-in, high-speed HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to high-voltage, high-current drive signals to properly drive the module's internal IGBTs. Separate negative IGBT terminals are available for each phase to support the widest variety of control algorithms.

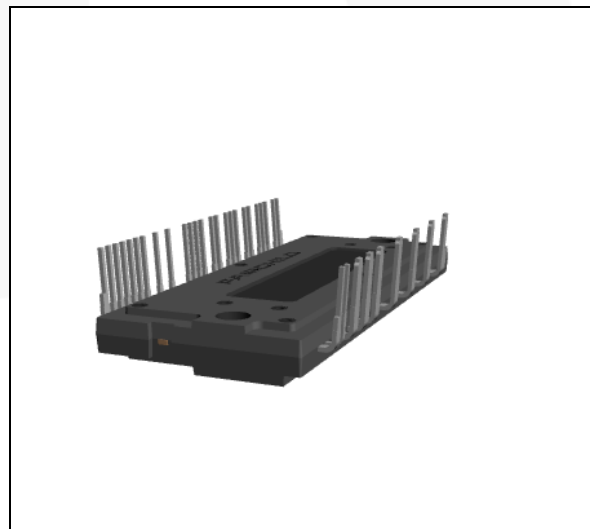


Figure 1. 3D Package Drawing
(Click to Activate 3D Content)

Package Marking and Ordering Information

Device	Device Marking	Package	Packing Type	Quantity
FNA27560	FNA27560	SPMCA-A34	Rail	6

Integrated Power Functions

- 600 V - 75 A IGBT inverter for three-phase DC / AC power conversion (refer to Figure 3)

Integrated Drive, Protection, and System Control Functions

- For inverter high-side IGBTs: gate-drive circuit, high-voltage isolated high-speed level-shifting control circuit, Under-Voltage Lock-Out Protection (UVLO), Available bootstrap circuit example is given in Figures 5 and 15.
- For inverter low-side IGBTs: gate-drive circuit, Short-Circuit Protection (SCP) control circuit, Under-Voltage Lock-Out Protection (UVLO)
- Fault signaling: corresponding to UV (low-side supply) and SC faults
- Input interface: active-HIGH interface, works with 3.3 / 5 V logic, Schmitt-trigger input

Pin Configuration

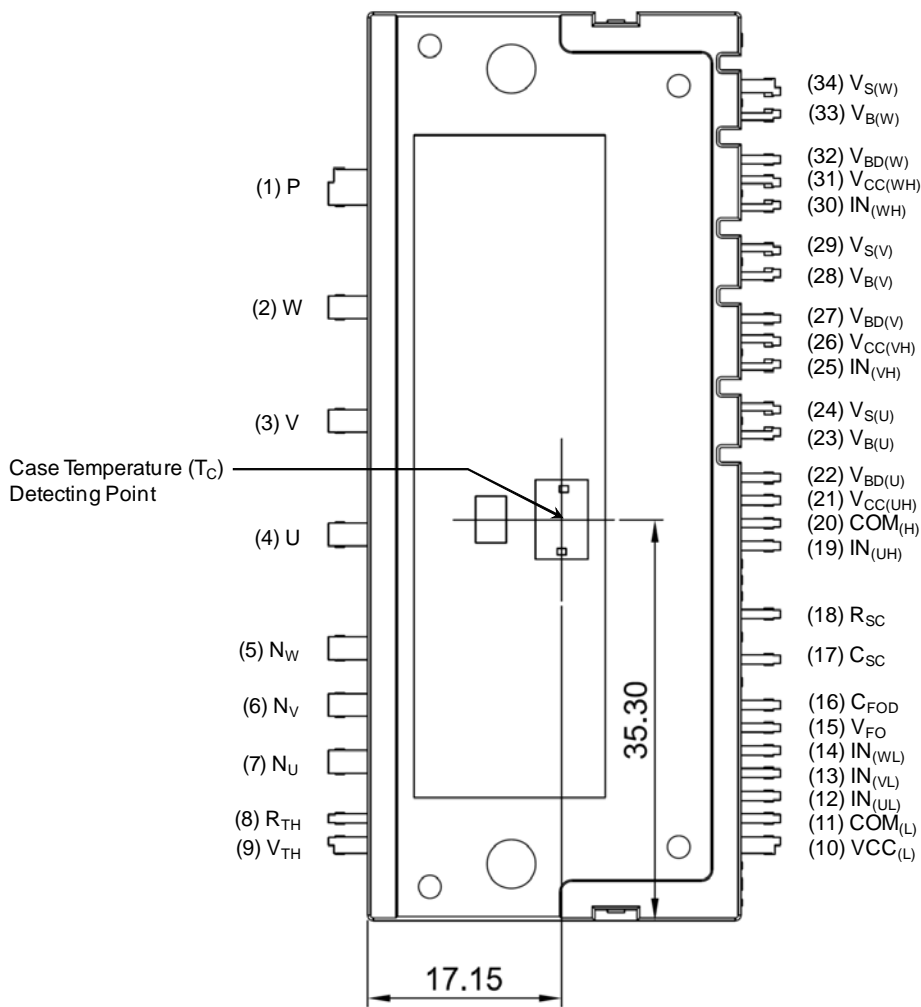


Figure 2. Top View

Pin Descriptions

Pin Number	Pin Name	Pin Description
1	P	Positive DC-Link Input
2	W	Output for W Phase
3	V	Output for V Phase
4	U	Output for U Phase
5	N _W	Negative DC-Link Input for W Phase
6	N _V	Negative DC-Link Input for V Phase
7	N _U	Negative DC-Link Input for U Phase
8	R _{TH}	Series Resistor for Thermistor (Temperature Detection)
9	V _{TH}	Thermistor Bias Voltage
10	V _{CC(L)}	Low-Side Bias Voltage for IC and IGBTs Driving
11	COM _(L)	Low-Side Common Supply Ground
12	IN _(UL)	Signal Input for Low-Side U Phase
13	IN _(VL)	Signal Input for Low-Side V Phase
14	IN _(WL)	Signal Input for Low-Side W Phase
15	V _{FO}	Fault Output
16	C _{FOD}	Capacitor for Fault Output Duration Selection
17	C _{SC}	Capacitor (Low-Pass Filter) for Short-Circuit Current Detection Input
18	R _{SC}	Resistor for Short-Circuit Current Detection
19	IN _(UH)	Signal Input for High-Side U Phase
20	COM _(H)	High-Side Common Supply Ground
21	V _{CC(UH)}	High-Side Bias Voltage for U Phase IC
22	V _{BD(U)}	Anode of Bootstrap Diode for U Phase High-Side Bootstrap Circuit
23	V _{B(U)}	High-Side Bias Voltage for U Phase IGBT Driving
24	V _{S(U)}	High-Side Bias Voltage Ground for U Phase IGBT Driving
25	IN _(VH)	Signal Input for High-Side V Phase
26	V _{CC(VH)}	High-Side Bias Voltage for V Phase IC
27	V _{BD(V)}	Anode of Bootstrap Diode for V Phase High-Side Bootstrap Circuit
28	V _{B(V)}	High-Side Bias Voltage for V Phase IGBT Driving
29	V _{S(V)}	High-Side Bias Voltage Ground for V Phase IGBT Driving
30	IN _(WH)	Signal Input for High-Side W Phase
31	V _{CC(WH)}	High-Side Bias Voltage for W Phase IC
32	V _{BD(W)}	Anode of Bootstrap Diode for W Phase High-Side Bootstrap Circuit
33	V _{B(W)}	High-Side Bias Voltage for W Phase IGBT Driving
34	V _{S(W)}	High-Side Bias Voltage Ground for W Phase IGBT Driving

Internal Equivalent Circuit and Input/Output Pins

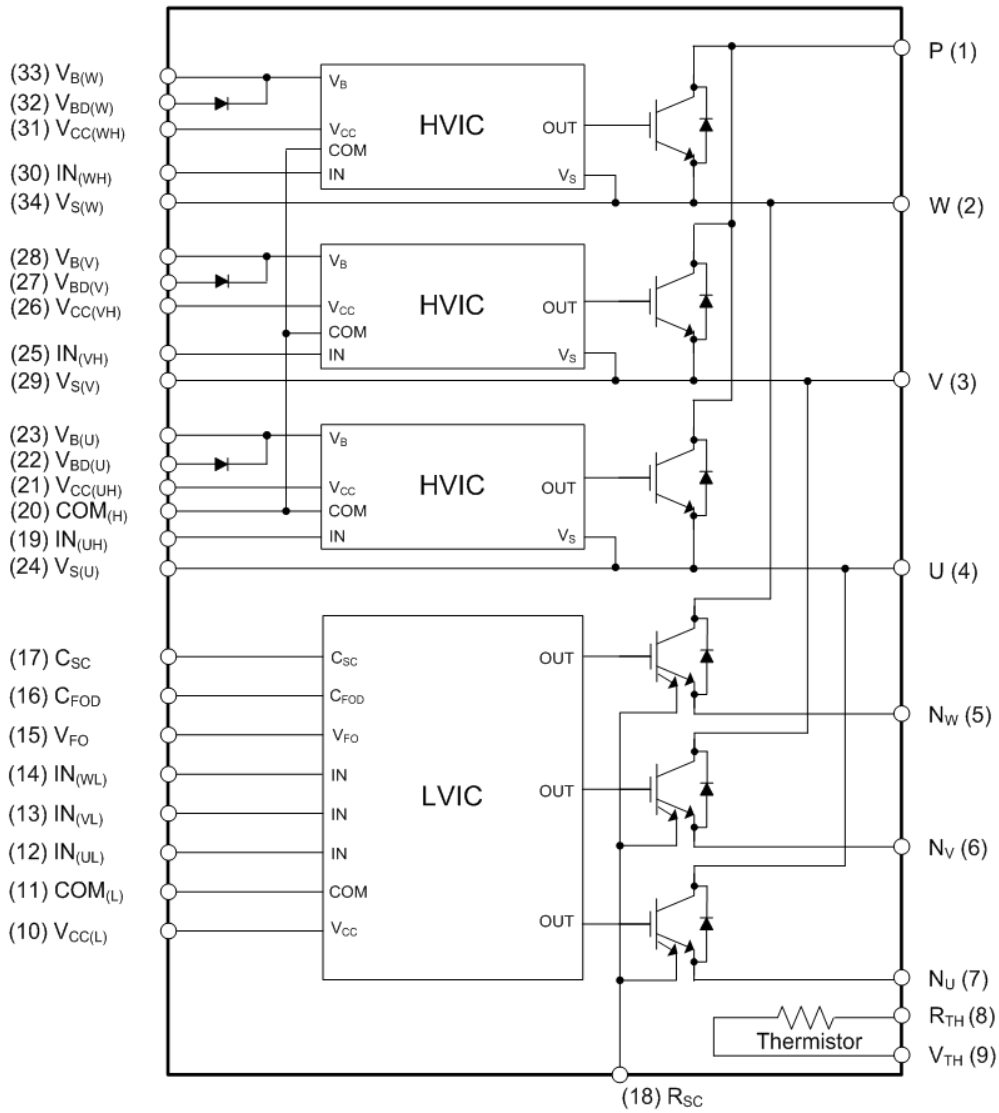


Figure 3. Internal Block Diagram

Notes:

1. Inverter high-side is composed of three normal-IGBTs, freewheeling diodes, and one control IC for each IGBT.
2. Inverter low-side is composed of three sense-IGBTs, freewheeling diodes, and one control IC for each IGBT. It has gate drive and protection functions.
3. Inverter power side is composed of four inverter DC-link input terminals and three inverter output terminals.



Absolute Maximum Ratings ($T_J = 25^\circ\text{C}$, unless otherwise specified.)**Inverter Part**

Symbol	Parameter	Conditions	Rating	Unit
V_{PN}	Supply Voltage	Applied between P - N_U , N_V , N_W	450	V
$V_{PN(\text{Surge})}$	Supply Voltage (Surge)	Applied between P - N_U , N_V , N_W	500	V
V_{CES}	Collector - Emitter Voltage		600	V
$\pm I_C$	Each IGBT Collector Current	$T_C = 25^\circ\text{C}$, $T_J \leq 150^\circ\text{C}$ (Note 4)	75	A
$\pm I_{CP}$	Each IGBT Collector Current (Peak)	$T_C = 25^\circ\text{C}$, $T_J \leq 150^\circ\text{C}$, Under 1 ms Pulse Width (Note 4)	150	A
P_C	Collector Dissipation	$T_C = 25^\circ\text{C}$ per One Chip (Note 4)	227	W
T_J	Operating Junction Temperature		-40 ~ 150	$^\circ\text{C}$

Control Part

Symbol	Parameter	Conditions	Rating	Unit
V_{CC}	Control Supply Voltage	Applied between $V_{CC(H)}$, $V_{CC(L)}$ - COM	20	V
V_{BS}	High-Side Control Bias Voltage	Applied between $V_{B(U)} - V_{S(U)}$, $V_{B(V)} - V_{S(V)}$, $V_{B(W)} - V_{S(W)}$	20	V
V_{IN}	Input Signal Voltage	Applied between $IN_{(UH)}$, $IN_{(VH)}$, $IN_{(WH)}$, $IN_{(UL)}$, $IN_{(VL)}$, $IN_{(WL)}$ - COM	-0.3 ~ $V_{CC}+0.3$	V
V_{FO}	Fault Output Supply Voltage	Applied between V_{FO} - COM	-0.3 ~ $V_{CC}+0.3$	V
I_{FO}	Fault Output Current	Sink Current at V_{FO} pin	2	mA
V_{SC}	Current Sensing Input Voltage	Applied between C_{SC} - COM	-0.3 ~ $V_{CC}+0.3$	V

Bootstrap Diode Part

Symbol	Parameter	Conditions	Rating	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage		600	V
I_F	Forward Current	$T_C = 25^\circ\text{C}$, $T_J \leq 150^\circ\text{C}$ (Note 4)	1.0	A
I_{FP}	Forward Current (Peak)	$T_C = 25^\circ\text{C}$, $T_J \leq 150^\circ\text{C}$, Under 1 ms Pulse Width (Note 4)	2.0	A
T_J	Operating Junction Temperature		-40 ~ 150	$^\circ\text{C}$

Total System

Symbol	Parameter	Conditions	Rating	Unit
$V_{PN(\text{PROT})}$	Self-Protection Supply Voltage Limit (Short-Circuit Protection Capability)	$V_{CC} = V_{BS} = 13.5 \sim 16.5 \text{ V}$, $T_J = 150^\circ\text{C}$, $V_{CES} < 600 \text{ V}$, Non-Repetitive, $< 2 \mu\text{s}$	400	V
T_C	Module Case Operation Temperature	See Figure 2	-40 ~ 125	$^\circ\text{C}$
T_{STG}	Storage Temperature		-40 ~ 125	$^\circ\text{C}$
V_{ISO}	Isolation Voltage	60 Hz, Sinusoidal, AC 1 Minute, Connection Pins to Heat Sink Plate	2500	V_{rms}

Thermal Resistance

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$R_{th(j-c)Q}$	Junction-to-Case Thermal Resistance (Note 5)	Inverter IGBT Part (per 1 / 6 Module)	-	-	0.55	$^\circ\text{C} / \text{W}$
$R_{th(j-c)F}$		Inverter FWD Part (per 1 / 6 Module)	-	-	1.00	$^\circ\text{C} / \text{W}$

Notes:

- These values had been made an acquisition by the calculation considered to design factor.
- For the measurement point of case temperature (T_C), please refer to Figure 2.

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified.)

Inverter Part

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit	
$V_{CE(SAT)}$	Collector - Emitter Saturation Voltage	$V_{CC} = V_{BS} = 15\text{ V}$ $V_{IN} = 5\text{ V}$	-	1.30	1.90	V	
V_F	FWDI Forward Voltage	$V_{IN} = 0\text{ V}$ $I_F = 50\text{ A}, T_J = 25^\circ\text{C}$	-	1.25	1.85	V	
HS	Switching Times	$V_{PN} = 300\text{ V}, V_{CC} = 15\text{ V}, I_C = 75\text{ A}$ $T_J = 25^\circ\text{C}$ $V_{IN} = 0\text{ V} \leftrightarrow 5\text{ V}$, Inductive Load See Figure 5 (Note 6)	t_{ON}	0.80	1.40	2.00	μs
			$t_{C(ON)}$	-	0.30	0.75	μs
			t_{OFF}	-	1.30	1.90	μs
			$t_{C(OFF)}$	-	0.20	0.65	μs
			t_{rr}	-	0.25	-	μs
LS	Switching Times	$V_{PN} = 300\text{ V}, V_{CC} = 15\text{ V}, I_C = 75\text{ A}$ $T_J = 25^\circ\text{C}$ $V_{IN} = 0\text{ V} \leftrightarrow 5\text{ V}$, Inductive Load See Figure 5 (Note 6)	t_{ON}	0.70	1.30	1.90	μs
			$t_{C(ON)}$	-	0.45	0.90	μs
			t_{OFF}	-	1.35	1.95	μs
			$t_{C(OFF)}$	-	0.30	0.75	μs
			t_{rr}	-	0.20	-	μs
I_{CES}	Collector - Emitter Leakage Current	$V_{CE} = V_{CES}$	-	-	5	mA	

Note:

6. t_{ON} and t_{OFF} include the propagation delay of the internal drive IC. $t_{C(ON)}$ and $t_{C(OFF)}$ are the switching times of IGBT under the given gate-driving condition internally. For the detailed information, please see Figure 4.

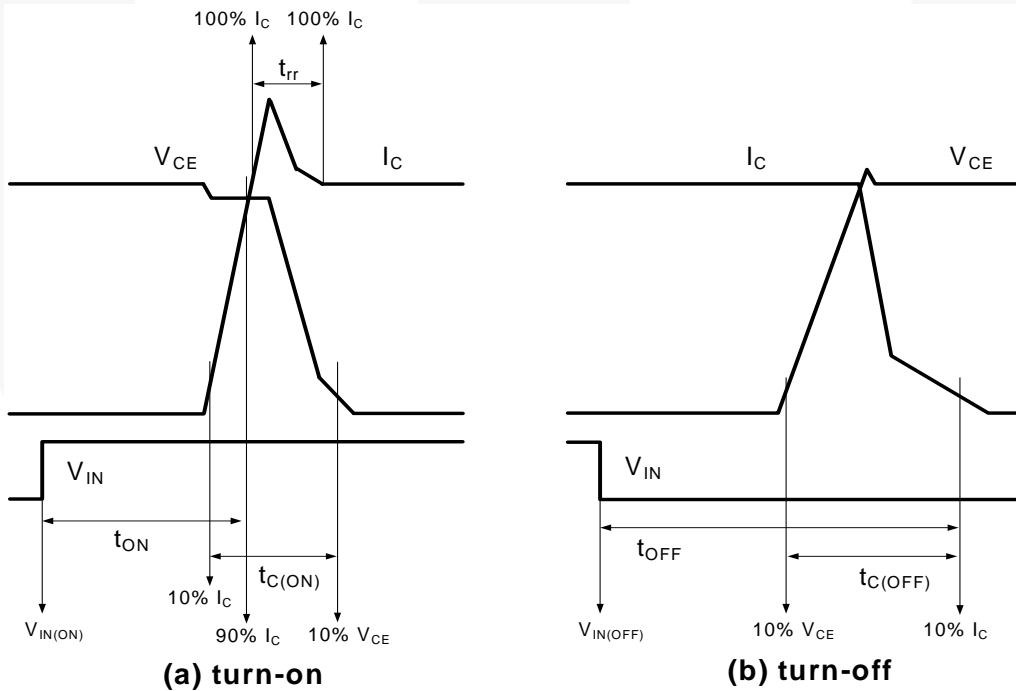


Figure 4. Switching Time Definition

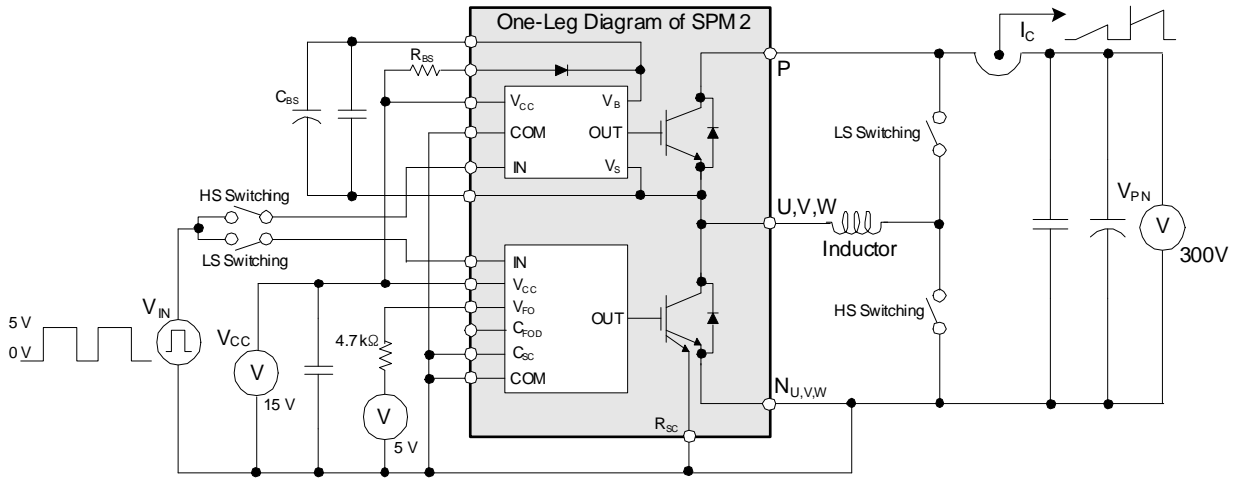


Figure 5. Example Circuit for Switching Test

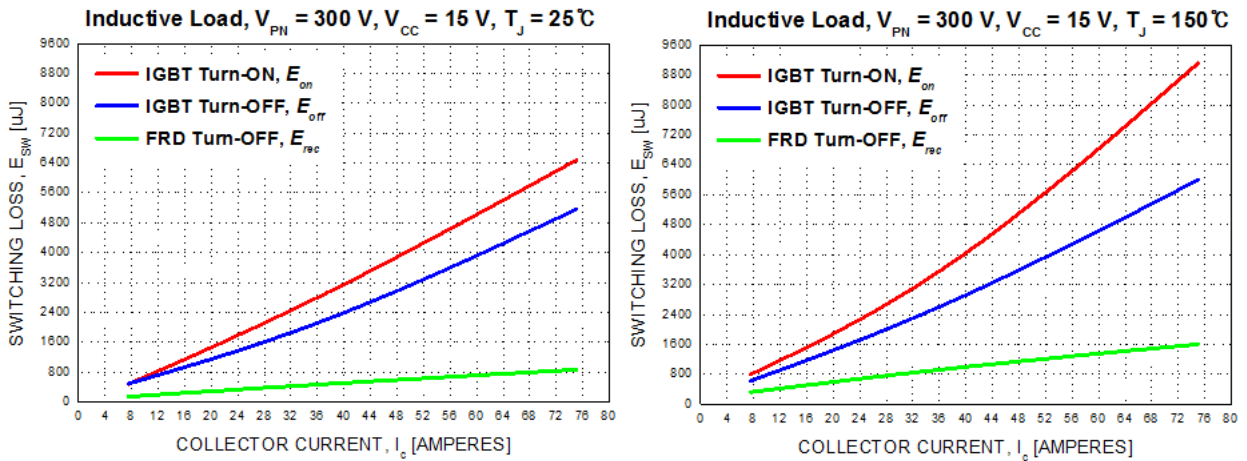


Figure 6. Switching Loss Characteristics (Typical)

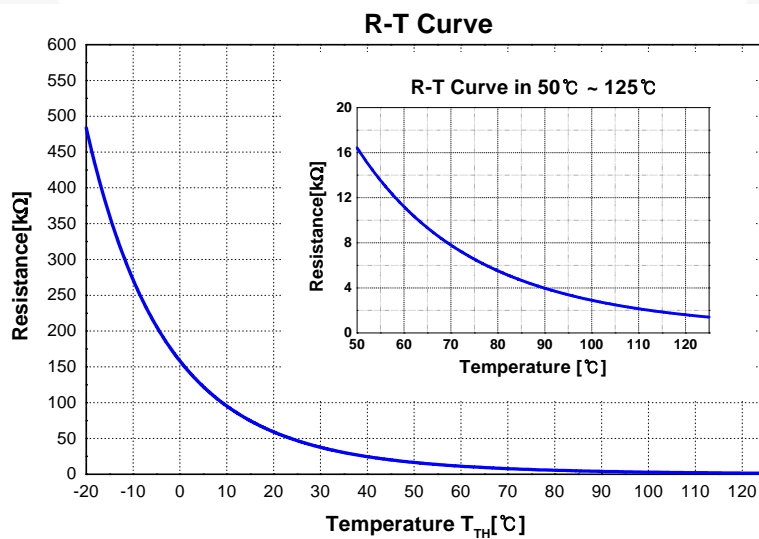


Figure 7. R-T Curve of Built-in Thermistor

Bootstrap Diode Part

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_F	Forward Voltage	$I_F = 1.0 \text{ A}$, $T_J = 25^\circ\text{C}$	-	2.2	-	V
t_{rr}	Reverse-Recovery Time	$I_F = 1.0 \text{ A}$, $dI_F / dt = 50 \text{ A} / \mu\text{s}$, $T_J = 25^\circ\text{C}$	-	80	-	ns

Control Part

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit	
I_{QCCH}	Quiescent V_{CC} Supply Current	$V_{CC(UH, VH, WH)} = 15 \text{ V}$, $I_{N(UH, VH, WH)} = 0 \text{ V}$	$V_{CC(UH)} - COM_{(H)}$, $V_{CC(VH)} - COM_{(H)}$, $V_{CC(WH)} - COM_{(H)}$	-	-	0.15	mA
I_{QCCL}		$V_{CC(L)} = 15 \text{ V}$, $I_{N(UL, VL, WL)} = 0 \text{ V}$	$V_{CC(L)} - COM_{(L)}$	-	-	5.00	mA
I_{PCCH}	Operating V_{CC} Supply Current	$V_{CC(UH, VH, WH)} = 15 \text{ V}$, $f_{PWM} = 20 \text{ kHz}$, Duty = 50%, Applied to one PWM Signal Input for High-Side	$V_{CC(UH)} - COM_{(H)}$, $V_{CC(VH)} - COM_{(H)}$, $V_{CC(WH)} - COM_{(H)}$	-	-	0.30	mA
I_{PCCL}		$V_{CC(L)} = 15 \text{ V}$, $f_{PWM} = 20 \text{ kHz}$, Duty = 50%, Applied to one PWM Signal Input for Low-Side	$V_{CC(L)} - COM_{(L)}$	-	-	9.00	mA
I_{QBS}	Quiescent V_{BS} Supply Current	$V_{BS} = 15 \text{ V}$, $I_{N(UH, VH, WH)} = 0 \text{ V}$	$V_{B(U)} - V_{S(U)}$, $V_{B(V)} - V_{S(V)}$, $V_{B(W)} - V_{S(W)}$	-	-	0.30	mA
I_{PBS}	Operating V_{BS} Supply Current	$V_{CC} = V_{BS} = 15 \text{ V}$, $f_{PWM} = 20 \text{ kHz}$, Duty = 50%, Applied to one PWM Signal Input for High-Side	$V_{B(U)} - V_{S(U)}$, $V_{B(V)} - V_{S(V)}$, $V_{B(W)} - V_{S(W)}$	-	-	6.50	mA
V_{FOH}	Fault Output Voltage	$V_{CC} = 15 \text{ V}$, $V_{SC} = 0 \text{ V}$, V_{FO} Circuit: 4.7 k Ω to 5 V Pull-up		4.5	-	-	V
V_{FOL}		$V_{CC} = 15 \text{ V}$, $V_{SC} = 1 \text{ V}$, V_{FO} Circuit: 4.7 k Ω to 5 V Pull-up		-	-	0.5	V
I_{SEN}	Sensing Current of Each Sense IGBT	$V_{CC} = 15 \text{ V}$, $V_{IN} = 5 \text{ V}$, $R_{SC} = 0 \Omega$, No Connection of Shunt Resistor at $N_{U, V, W}$ Terminal	$I_C = 75 \text{ A}$	-	28	-	mA
$V_{SC(ref)}$	Short Circuit Trip Level	$V_{CC} = 15 \text{ V}$ (Note 7)	$C_{SC} - COM_{(L)}$	0.43	0.50	0.57	V
I_{SC}	Short Circuit Current Level for Trip	$R_{SC} = 11 \Omega$ ($\pm 1\%$), No Connection of Shunt Resistor at $N_{U, V, W}$ Terminal (Note 7)		-	150	-	A
UV_{CCD}	Supply Circuit Under-Voltage Protection	Detection Level		10.3	-	12.8	V
UV_{CCR}		Reset Level		10.8	-	13.3	V
UV_{BSD}		Detection Level		9.5	-	12.0	V
UV_{BSR}		Reset Level		10.0	-	12.5	V
t_{FOD}	Fault-Out Pulse Width	$C_{FOD} = \text{Open}$	(Note 8)	50	-	-	μs
		$C_{FOD} = 2.2 \text{ nF}$		1.7	-	-	ms
$V_{IN(ON)}$	ON Threshold Voltage	Applied between $I_{N(UH, VH, WH)} - COM_{(H)}$, $I_{N(UL, VL, WL)} - COM_{(L)}$		-	-	2.6	V
$V_{IN(OFF)}$	OFF Threshold Voltage			0.8	-	-	V
R_{TH}	Resistance of Thermistor	at $T_{TH} = 25^\circ\text{C}$	See Figure 7 (Note 9)	-	47	-	k Ω
		at $T_{TH} = 100^\circ\text{C}$		-	2.9	-	k Ω

Notes:

- Short-circuit current protection functions only at the low-sides because the sense current is divided from main current at low-side IGBTs. Inserting the shunt resistor for monitoring the phase current at N_U , N_V , N_W terminal, the trip level of the short-circuit current is changed.
- The fault-out pulse width t_{FOD} depends on the capacitance value of C_{FOD} according to the following approximate equation : $t_{FOD} = 0.8 \times 10^6 \times C_{FOD} \text{ [s]}$.
- T_{TH} is the temperature of thermistor itself. To know case temperature (T_C), conduct experiments considering the application.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Value			Unit
			Min.	Typ.	Max.	
V_{PN}	Supply Voltage	Applied between P - N_U, N_V, N_W	-	300	400	V
V_{CC}	Control Supply Voltage	Applied between $V_{CC(UH, VH, WH)} - COM_{(H)}, V_{CC(L)} - COM_{(L)}$	14.5	15.0	16.5	V
V_{BS}	High-Side Bias Voltage	Applied between $V_{B(U)} - V_{S(U)}, V_{B(V)} - V_{S(V)}, V_{B(W)} - V_{S(W)}$	13.5	15.0	18.5	V
$dV_{CC}/dt, dV_{BS}/dt$	Control Supply Variation		-1	-	1	V / μ s
t_{dead}	Blanking Time for Preventing Arm - Short	For Each Input Signal	2.0	-	-	μ s
f_{PWM}	PWM Input Signal	$-40^\circ\text{C} \leq T_C \leq 125^\circ\text{C}, -40^\circ\text{C} \leq T_J \leq 150^\circ\text{C}$	-	-	20	kHz
V_{SEN}	Voltage for Current Sensing	Applied between $N_U, N_V, N_W - COM_{(H, L)}$ (Including Surge Voltage)	-5	-	5	V
$PW_{IN(ON)}$	Minimum Input Pulse Width	$V_{CC} = V_{BS} = 15\text{ V}, I_C \leq 150\text{ A}$, Wiring Inductance between N_U, v, w and DC Link N < 10nH (Note 10)	3.0	-	-	μ s
$PW_{IN(OFF)}$			3.0	-	-	
T_J	Junction Temperature		-40	-	150	$^\circ\text{C}$

Note:

10. This product might not make right output response if input pulse width is less than the recommended value.

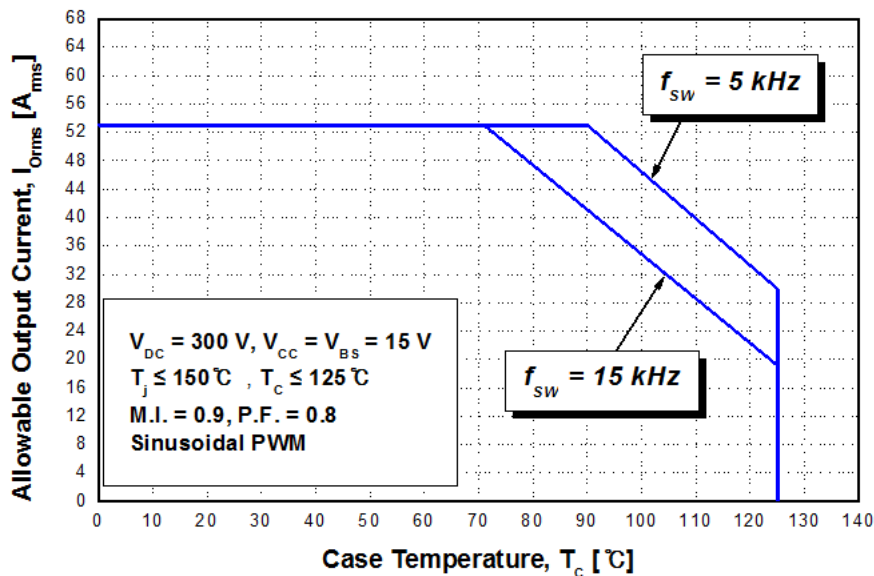


Figure 8. Allowable Maximum Output Current

Note:

11. This allowable output current value is the reference data for the safe operation of this product. This may be different from the actual application and operating condition.

Mechanical Characteristics and Ratings

Parameter	Conditions	Min.	Typ.	Max.	Unit	
Device Flatness	See Figure 9	0	-	+200	μm	
Mounting Torque	Mounting Screw: M4	Recommended 1.0 N • m	0.9	1.0	1.5	N • m
	See Figure 10	Recommended 10.1 kg • cm	9.1	10.1	15.1	kg • cm
Terminal Pulling Strength	Load 19.6 N	10	-	-	s	
Terminal Bending Strength	Load 9.8 N, 90 degrees Bend	2	-	-	times	
Weight		-	50	-	g	

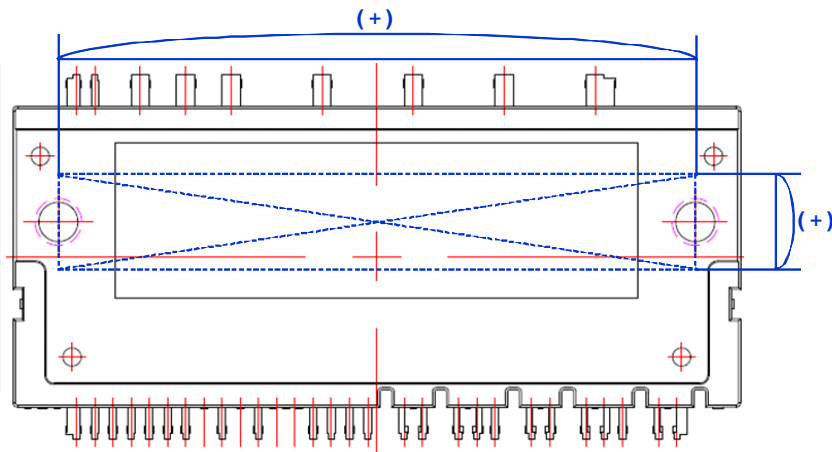


Figure 9. Flatness Measurement Position

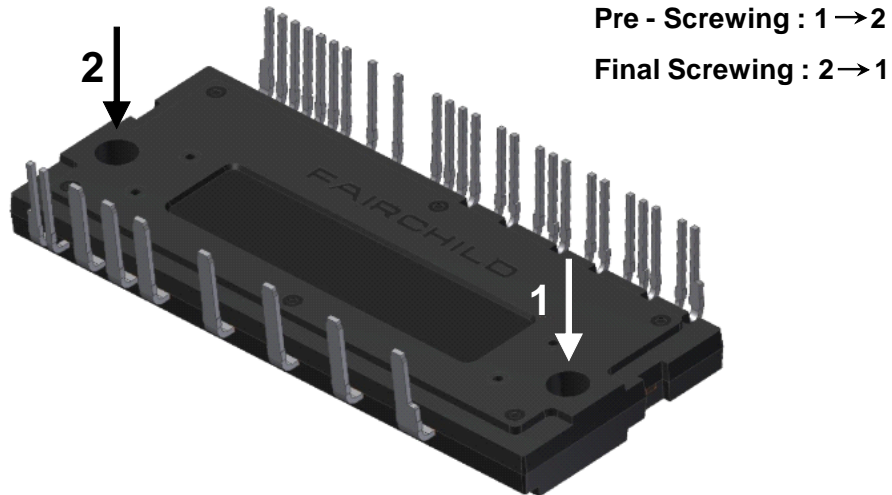


Figure 10. Mounting Screws Torque Order

Notes:

- 12. Do not over torque when mounting screws. Too much mounting torque may cause DBC cracks, as well as bolts and Al heat-sink destruction.
- 13. Avoid one-sided tightening stress. Figure 10 shows the recommended torque order for the mounting screws. Uneven mounting can cause the DBC substrate of package to be damaged. The pre-screwing torque is set to 20 ~ 30% of maximum torque rating.

Time Charts of SPMs Protective Function

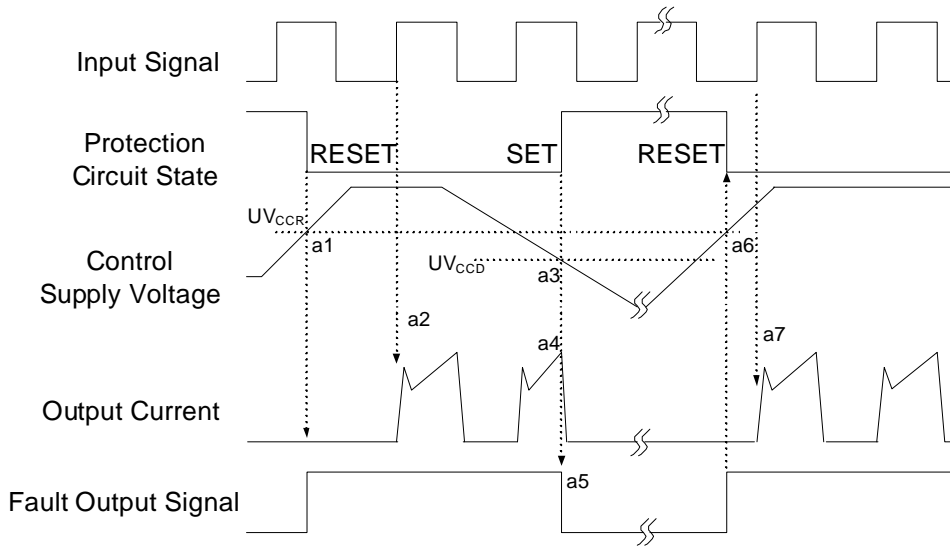


Figure 11. Under-Voltage Protection (Low-Side)

- a1 : Control supply voltage rises: after the voltage rises UV_{CCR} , the circuits start to operate when the next input is applied.
- a2 : Normal operation: IGBT ON and carrying current.
- a3 : Under-voltage detection (UV_{CCD}).
- a4 : IGBT OFF in spite of control input condition.
- a5 : Fault output operation starts with a fixed pulse width according to the condition of the external capacitor C_{FOD} .
- a6 : Under-voltage reset (UV_{CCR}).
- a7 : Normal operation: IGBT ON and carrying current by triggering next signal from LOW to HIGH.

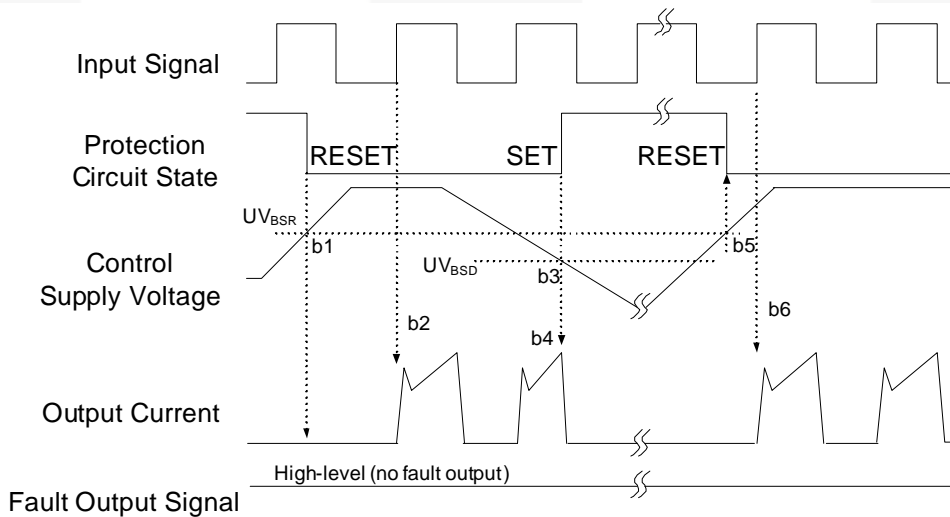


Figure 12. Under-Voltage Protection (High-Side)

- b1 : Control supply voltage rises: after the voltage reaches UV_{BSR} , the circuits start to operate when the next input is applied.
- b2 : Normal operation: IGBT ON and carrying current.
- b3 : Under-voltage detection (UV_{BSD}).
- b4 : IGBT OFF in spite of control input condition, but there is no fault output signal.
- b5 : Under-voltage reset (UV_{BSR}).
- b6 : Normal operation: IGBT ON and carrying current by triggering next signal from LOW to HIGH.

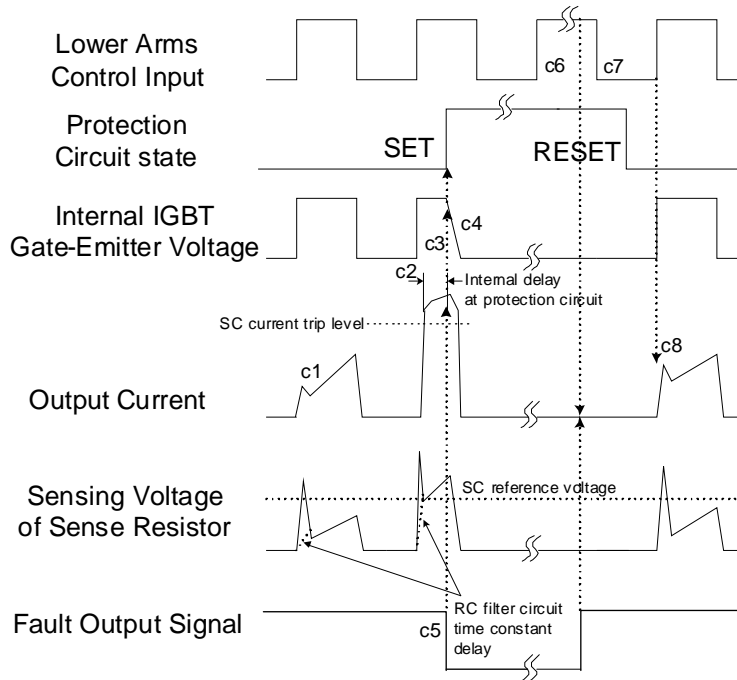


Figure 13. Short-Circuit Current Protection (Low-Side Operation only)

(with the external sense resistance and RC filter connection)

- c1 : Normal operation: IGBT ON and carrying current.
- c2 : Short-circuit current detection (SC trigger).
- c3 : All low-side IGBTs gate are hard interrupted.
- c4 : All low-side IGBTs turn OFF.
- c5 : Fault output operation starts with a fixed pulse width according to the condition of the external capacitor C_{FOD} .
- c6 : Input HIGH: IGBT ON state, but during the active period of fault output, the IGBT doesn't turn ON.
- c7 : Fault output operation finishes, but IGBT doesn't turn on until triggering the next signal from LOW to HIGH.
- c8 : Normal operation: IGBT ON and carrying current.

Input/Output Interface Circuit

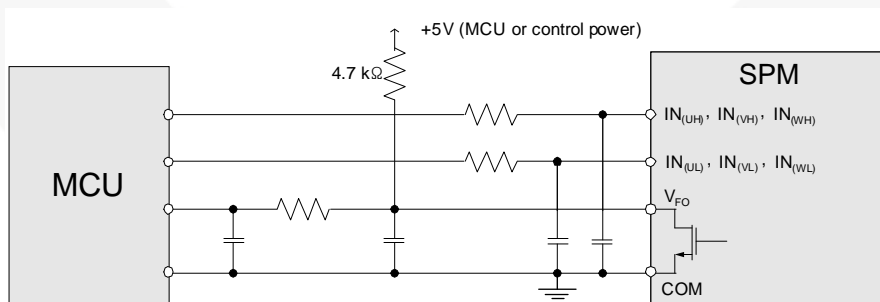
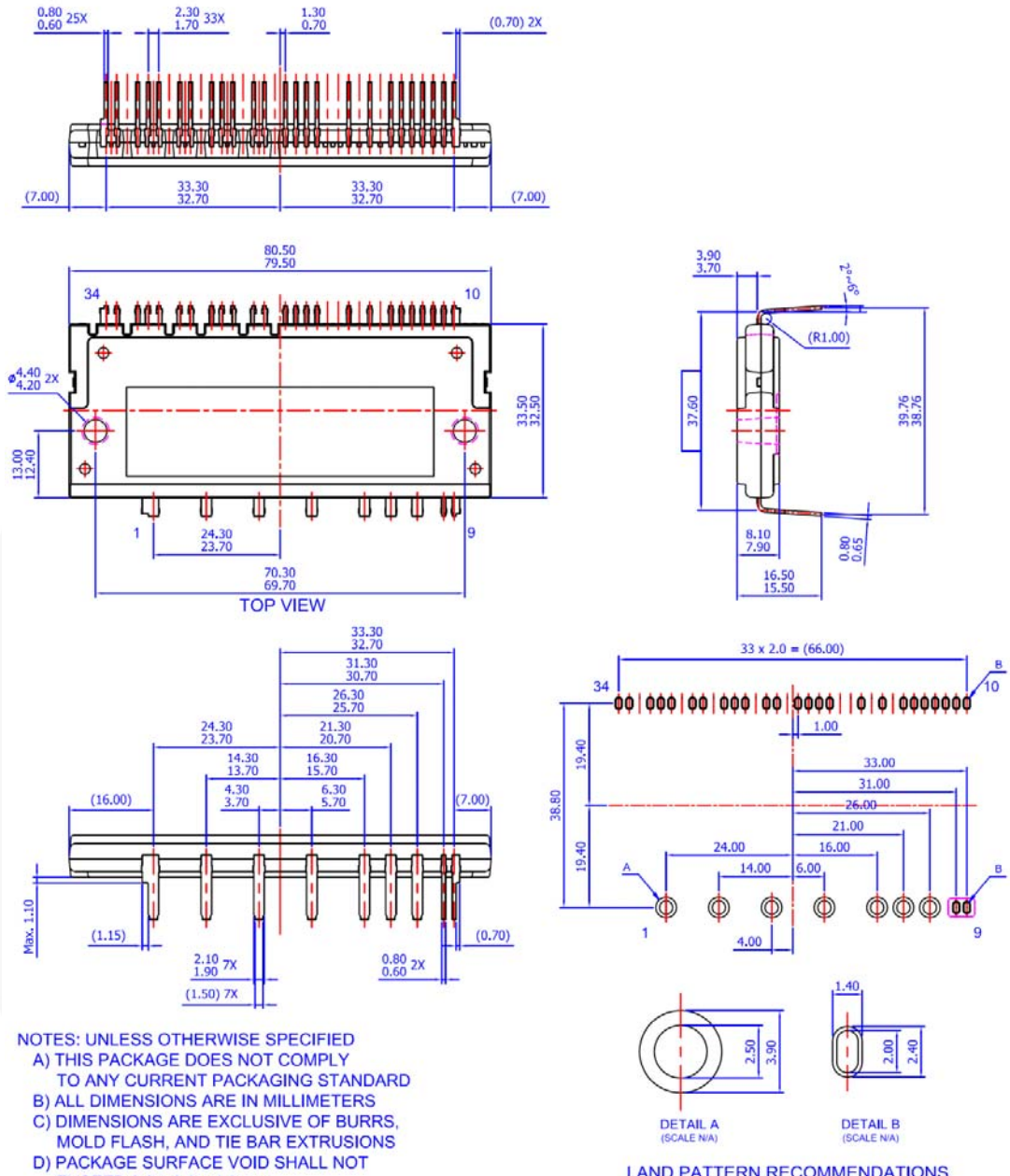


Figure 14. Recommended MCU I/O Interface Circuit

Note:

14. RC coupling at each input might change depending on the PWM control scheme used in the application and the wiring impedance of the application's printed circuit board. The input signal section of the Motion SPM 2 product integrates 5 kΩ (typ.) pull-down resistor. Therefore, when using an external filtering resistor, please pay attention to the signal voltage drop at input terminal.

Detailed Package Outline Drawings (FNA27560)



- NOTES: UNLESS OTHERWISE SPECIFIED
 A) THIS PACKAGE DOES NOT COMPLY TO ANY CURRENT PACKAGING STANDARD
 B) ALL DIMENSIONS ARE IN MILLIMETERS
 C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
 D) PACKAGE SURFACE VOID SHALL NOT EXCEED 2.3 x 2.3 x 1.0mm
 E) () IS REFERENCE
 F) [] IS ASS'Y QUALITY
 G) DRAWING FILENAME: MOD34BAREV2.0
 H) FAIRCHILD SEMICONDUCTOR

LAND PATTERN RECOMMENDATIONS

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or data on the drawing and contact a FairchildSemiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide therm and conditions, specifically the the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

<http://www.fairchildsemi.com/dwg/MO/MOD34BA.pdf>



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

- | | | | |
|--------------------------|--|---------------------------------------|------------------|
| AccuPower™ | F-PFS™ | OPTOPLANAR® | SYSTEM GENERAL® |
| AttitudeEngine™ | FRFET® | ® | TinyBoost® |
| Awinda® | Global Power Resource™ | Power Supply WebDesigner™ | TinyBuck® |
| AX-CAP®* | GreenBridge™ | PowerTrench® | TinyCalc™ |
| BitSiC™ | Green FPS™ | PowerXS™ | TinyLogic® |
| Build it Now™ | Green FPS™ e-Series™ | Programmable Active Droop™ | TINYOPTO™ |
| CorePLUS™ | Gmax™ | QFET® | TinyPower™ |
| CorePOWER™ | GTO™ | QS™ | TinyPWM™ |
| CROSSVOLT™ | IntelliMAX™ | Quiet Series™ | TinyWire™ |
| CTL™ | ISOPLANAR™ | RapidConfigure™ | TranSiC™ |
| Current Transfer Logic™ | Making Small Speakers Sound Louder and Better™ | ™ | TriFault Detect™ |
| DEUXPEED® | MegaBuck™ | Saving our world, 1mW/W/kW at a time™ | TRUECURRENT®* |
| Dual Cool™ | MICROCOUPLER™ | SignalWise™ | μSerDes™ |
| EcoSPARK® | MicroFET™ | SmartMax™ | SerDes™ |
| EfficientMax™ | MicroPak™ | SMART START™ | UHC™ |
| ESBC™ | MicroPak2™ | Solutions for Your Success™ | Ultra FRFET™ |
| Fairchild® | MillerDrive™ | SPM® | UniFET™ |
| Fairchild Semiconductor® | MotionMax™ | STEALTH™ | VCX™ |
| FACT Quiet Series™ | MotionGrid® | SuperFET® | VisualMax™ |
| FACT® | MTI® | SuperSOT™-3 | VoltagePlus™ |
| FastvCore™ | MTx® | SuperSOT™-6 | XS™ |
| FETBench™ | MVN® | SuperSOT™-8 | Xsens™ |
| FPS™ | mWSaver® | SupreMOS® | 仙童® |
| | OptoHiT™ | SyncFET™ | |
| | OPTOLOGIC® | Sync-Lock™ | |

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT [HTTP://WWW.FAIRCHILDSEMI.COM](http://www.fairchildsemi.com). FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 177

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>
For additional information, please contact your local
Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[ON Semiconductor:](#)

[FNA27560](#)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.